74HC3G34; 74HCT3G34 Triple buffer gate Rev. 7 — 11 June 2018

Product data sheet

1 **General description**

The 74HC3G34; 74HCT3G34 is a triple buffer. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

Features and benefits 2

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC3G34: CMOS level
 - For 74HCT3G34: TTL level
- Complies with JEDEC standard no. 7 A
- Symmetrical output impedance
- · High noise immunity
- Low-power dissipation
- Balanced propagation delays
- Multiple package options
- ESD protection:
 - HBM JESD22-A114E exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3 Ordering information

Table 1. Ordering information											
Type number Package											
	Temperature range	Name	Description	Version							
74HC3G34DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads;	SOT505-2							
74HCT3G34DP	_		body width 3 mm; lead length 0.5 mm								
74HC3G34DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package;	SOT765-1							
74HCT3G34DC			8 leads; body width 2.3 mm								

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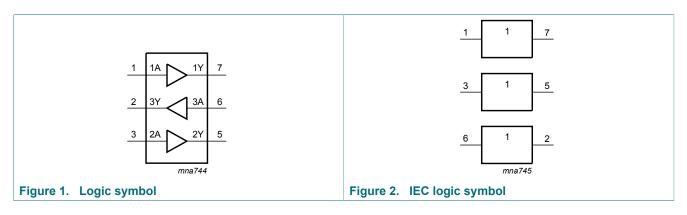
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4 Marking

Table 2. Marking						
Type number	Marking code ^[1]					
74HC3G34DP	H34					
74HCT3G34DP	T34					
74HC3G34DC	P34					
74HCT3G34DC	U34					

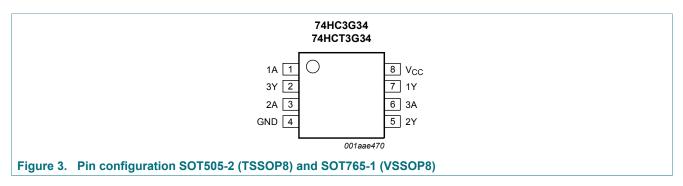
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5 Functional diagram



6 **Pinning information**

6.1 Pinning



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6.2 Pin description

Symbol	Pin	Description
1A, 2A, 3A	1, 3, 6	data input
1Y, 2Y, 3Y	7, 5, 2	data output
GND	4	ground (0 V)
V _{CC}	8	supply voltage

Functional description 7

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
nA	nY
L	L
Н	Н

Limiting values 8

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V ^[1]] _	±20	mA
I _{ОК}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V ^[1]] _	±20	mA
I _O	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)	-	±25	mA
I _{CC}	quiescent supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C ^{[2}] _	300	mW

For VSSOP8 package: above 110 °C the value of Ptot derates linearly with 8 mW/K.

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9 Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	Conditions 74HC3G34		7	Unit			
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	and fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

10 Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C t	Unit	
				Typ ^[1]	Max	Min	Мах	
74HC3G3	4					1	1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	V
V _{OH} HIGH-level output	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	V
		I_{O} = -20 µA; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
		I_0 = -5.2 mA; V_{CC} = 6.0 V	5.63	5.81	-	5.2	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_0 = 20 µA; V_{CC} = 2.0 V	-	0	0.1	-	0.1	V
		I_{O} = 20 µA; V_{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I_{O} = 20 µA; V_{CC} = 6.0 V	-	0	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.33	-	0.4	V
I	input leakage current	V_{I} = V_{CC} or GND; V_{CC} = 6.0 V	-	-	±1.0	-	±1.0	μA

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Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C t	Unit	
			Min	Typ ^[1]	Мах	Min	Max	
I _{CC}	supply current	per input pin; V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	10	-	20	μA
CI	input capacitance		-	1.5	-	-	-	pF
74HCT3G	34		1		I	1		
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	V
VIL	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_{O} = -20 µA; V_{CC} = 4.5 V	4.4	4.5	-	4.4	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	4.13	4.32	-	3.7	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}$						
	voltage	I_{O} = 20 µA; V_{CC} = 4.5 V	-	0	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.33	-	0.4	V
l _l	input leakage current	V_{I} = V_{CC} or GND; V_{CC} = 5.5 V	-	-	±1.0	-	±1.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	10	-	20	μA
ΔI _{CC}	additional supply current	per input; V_{CC} = 4.5 V to 5.5 V; V _I = V _{CC} - 2.1 V; I _O = 0 A	-	-	375	-	410	μA
CI	input capacitance		-	1.5	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 $^\circ C.$

11 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 5.

Symbol	Parameter	Conditions		-40	°C to +85	5 °C	-40 °C t	o +125 °C	Unit
				Min	Typ ^[1]	Мах	Min	Мах	
74HC3G	34	1						1	
t _{pd}	propagation delay	nA to nY; see Figure 4	[2]						
		V _{CC} = 2.0 V		-	29	95	-	125	ns
		V _{CC} = 4.5 V		-	9	19	-	25	ns
		V _{CC} = 6.0 V		-	8	16	-	20	ns
t _t	transition time	nY; see Figure 4	[3]						
		V _{CC} = 2.0 V		-	18	95	-	125	ns
		V _{CC} = 4.5 V		-	6	19	-	25	ns
		V _{CC} = 6.0 V		-	5	16	-	20	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[4]	-	10	-	-	-	pF

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Symbol Parameter		Conditions		-40 °C to +85 °C			-40 °C t	Unit	
				Min	Typ ^[1]	Мах	Min	Max	
74HCT3	G34		L				1		-
t _{pd}	propagation delay	nA to nY; see Figure 4	[2]						
		V _{CC} = 4.5 V		-	10	23	-	29	ns
t _t	transition time	nY; V _{CC} = 4.5 V; see <u>Figure 4</u>	[3]	-	6	19	-	25	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC} - 1.5 V	[4]	-	9	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 °C.

[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

[4] t_{i} is the same as t_{TH} and t_{THL} . [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

11.1 Waveform and test circuit

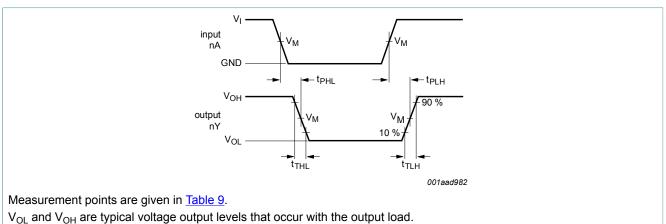


Figure 4. Propagation delay data input (nA) to data output (nY) and transition time output (nY)

Table 9. Measurement points

Туре	Input	Output
	V _M	V _M
74HC3G34	0.5 x V _{CC}	0.5 x V _{CC}
74HCT3G34	1.3 V	1.3 V

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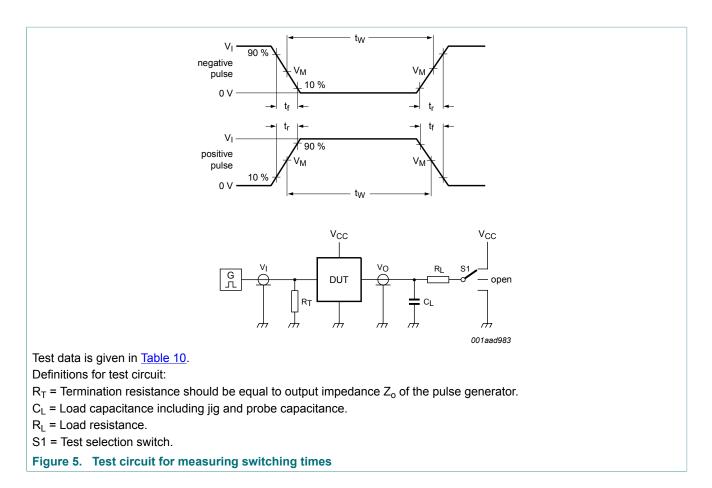


Table 10. Test data

Туре	Input Load		Load		S1 position
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}
74HC3G34	GND to V _{CC}	≤ 6 ns	50 pF	1 kΩ	open
74HCT3G34	GND to 3 V	≤ 6 ns	50 pF	1 kΩ	open

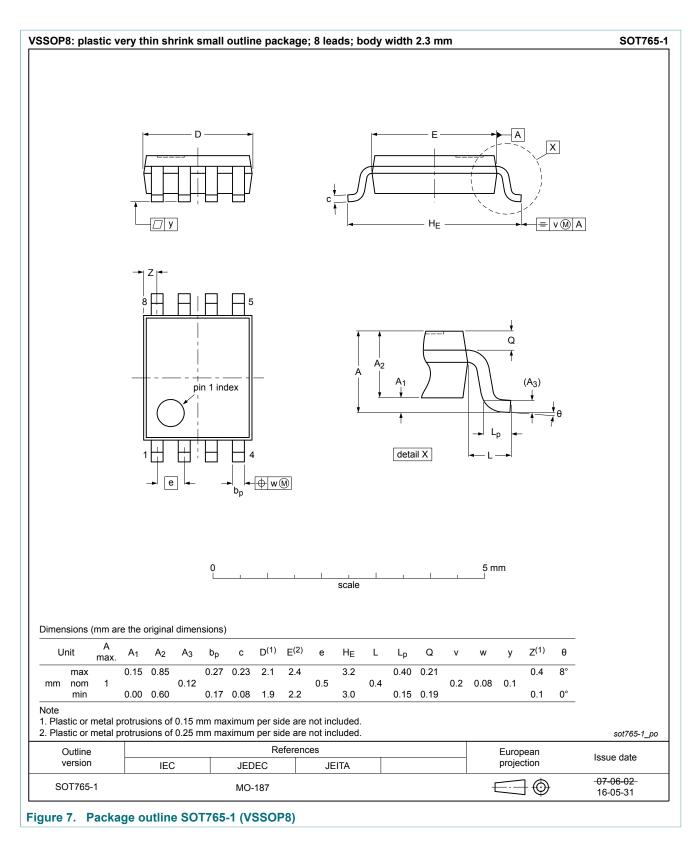
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12 Package outline

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13 Abbreviations

Table 11. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MM	Machine Model				
TTL	Transistor-Transistor Logic				

14 Revision history

Table 12. Revision history **Document ID Release date** Data sheet status Change notice Supersedes 74HC HCT3G34 v.7 20180611 Product data sheet 74HC HCT3G34 v.6 Modifications: · The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. • Legal texts have been adapted to the new company name where appropriate. • Type numbers 74HC3G34GD and 74HCT3G34GD removed. 74HC HCT3G34 v.6 20131211 Product data sheet 74HC HCT3G34 v.5 _ • For type numbers 74HC3G34GD and 74HCT3G34GD XSON8U has changed to XSON8. Modifications: 74HC HCT3G34 v.5 Product data sheet 20090507 74HC HCT3G34 v.4 _ 74HC HCT3G34 v.4 20060309 Product data sheet 74HC HCT3G34 v.3 _ 74HC_HCT3G34 v.3 20030519 Product specification 74HC_HCT3G34 v.2 _ 74HC_HCT3G34 v.2 74HC HCT3G34 v.1 20030210 Product specification _ 74HC_HCT3G34 v.1 20031003 Product specification

15 Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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The term 'short data sheet' is explained in section "Definitions".

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